# Hyperfast Rectifier, 60 A FRED Pt<sup>®</sup> Gen 5



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# LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	60 A							
V <sub>R</sub>	1200 V							
V <sub>F</sub> at I <sub>F</sub> at 125 °C	2.1 V							
t <sub>rr</sub>	30 ns							
T <sub>J</sub> max.	175 °C							
Package	TO-247AD 2L							
Circuit configuration	Single							

## **FEATURES**

- Hyperfast and optimized Q<sub>rr</sub>
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

# **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

### **MECHANICAL DATA**

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V <sub>RRM</sub>		1200	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 101 °C, D = 0.50	60							
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 45 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	370	А						
Repetitive peak forward current	I <sub>FRM</sub>	T <sub>C</sub> = 101 °C, D = 0.50, f = 20 kHz	120							
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	MIN.	TYP.	MAX.	UNITS						
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	1200	-	-					
Ferryard valtage	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	2.6	3.3	V				
Forward voltage		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	2.1	-					
Reverse leakage current	1	$V_{R} = V_{R}$ rated	-	-	50					
neverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	500		μA					
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	32	-	pF				
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH				

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RoHS COMPLIANT HALOGEN FREE



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	100 A/ $\mu$ s, V <sub>R</sub> = 30 V	-	30	-				
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	120	-	ns			
		T <sub>J</sub> = 125 °C		-	170	-				
Peak recovery current		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 40 A dI <sub>F</sub> /dt = 600 A/μs	-	17	-	A			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	32	-				
Deveryon and a second schemes	0	T <sub>J</sub> = 25 °C		-	970	-	nC			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	2950	-				
Reverse recovery time	+	T <sub>J</sub> = 25 °C		-	90	-	ns			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	130	-				
Poak receivery ourrent	1	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 60 A dI <sub>F</sub> /dt = 1000 A/μs	-	32	-	А			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$V_{\rm R} = 800  \rm V$	-	53	-				
	0	T <sub>J</sub> = 25 °C	1	-	1570	-				
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	1	-	4300	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	0.4	°C/W				
Weight			-	5.5	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C				
Marking device		Case style: TO-247AD 2L	E5PX6012LH							

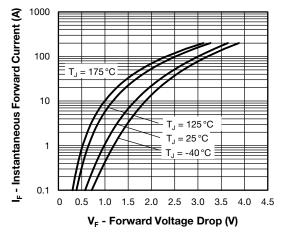


Fig. 1 - Typical Forward Voltage Drop Characteristics

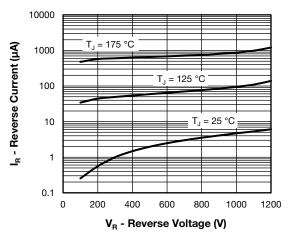
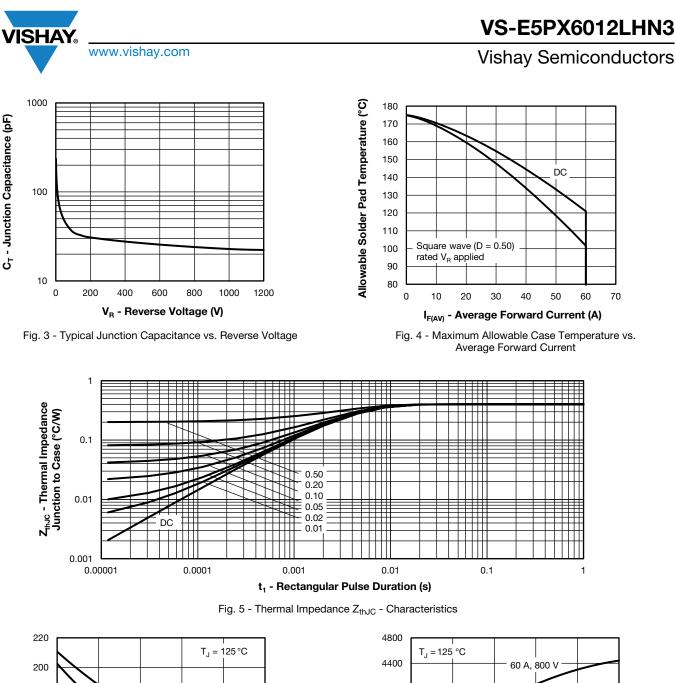


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





60 A, 800 V dl<sub>F</sub>/dt (A/µs)

Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Q<sub>rr</sub> (nC) 40 A, 400 V dl<sub>F</sub>/dt (A/µs)

Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

40 A, 400 V

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# VS-E5PX6012LHN3

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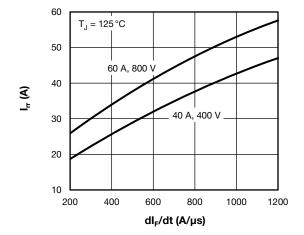


Fig. 8 - Typical Recovery Current vs. dl<sub>F</sub>/dt

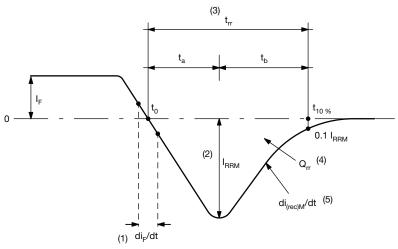


Fig. 9 - Reverse Recovery Waveform and Definitions

#### Notes

- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- <sup>(2)</sup> I<sub>RRM</sub> peak reverse recovery current
- $^{(3)}$  t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RRM</sub>
- $^{(4)}~Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10~\%}$

$$Q_{rr} = \int^{t_{10\%}} I(t) dt$$

t<sub>o</sub>  $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>



## **ORDERING INFORMATION TABLE**

Device code	vs-	Е	5	Р	x	60	12	L	Н	N3
	1	2	3	4	5	6	7	8	9	10
	1 - 2 -									
	3 - 4 - 5 -	<ul> <li>FRED Pt Gen 5</li> <li>P = TO-247 package</li> <li>Process type: X = hyperfast recovery</li> </ul>								
		<ul> <li>Current rating (60 = 60 A)</li> <li>Voltage rating (12 = 1200 V)</li> <li>L = long lead</li> </ul>								
	10 -			ital digit: en-free,		ompliar	nt, and t	otally le	ad (Pb)	-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	Y PACKAGING DESCRIPTION					
VS-E5PX6012LHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95536							
Part marking information	www.vishay.com/doc?95648						
SPICE model	www.vishay.com/doc?96556						



**TO-247AD 2L** 

## **DIMENSIONS** in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIMETERS INCHES		NOTES SYMBOL	SYMBOL	MILLIMETERS		INCHES		NOTES			
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053				•		•		•

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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